# MSKSEMI















**ESD** 

**TVS** 

**TSS** 

MOV

**GDT** 

**PLED** 

Broduct data speet

SMXXT1G-MS









#### **FEATURES**

- We declare that the material of product compliance with RoHS requirements and Halogen Free.
- S- prefix for automotive and other applications requiring unique site and control change requirements; AEC-Q101 qualified and PPAP capable.
- 2 Unidirectional transil functions
- Low leakage current:IR max< 20 µA at VRM
- 300W peak pulse power(8/20µs)
- Transient protection for data lines as per IEC61000-4-2(ESD) 15KV(air)8KV(contact) IEC61000-4-5(Lightning) see IPPM below

### **APPLICATIONS**

- Computers
- Printers
- Communication systems



SOT-23

## **ELECTRICAL CHARACTERISTICS (Ta= 25°C)**

P/N	V <sub>BR</sub>						С
	Min.	Тур.	Max.	I <sub>T</sub>	$V_{RWM}$	I <sub>R</sub>	Typ. 0v bias
	V	V	V	mA	V	μA	pF
SM05T1G-MS	6.0	6.7	7.4	1	5.0	1	30
SM12T1G-MS	13.3	14.0	14.7	1	12.0	1	25
SM15T1G-MS	16.7	17.4	18.1	1	15.0	1	25
SM24T1G-MS	26.7	28.2	29.6	1	24.0	1	20

<sup>1).8/20</sup> waveform used. (see fig2.)

## **ABSOLUTE RATINGS(Ta = 25°C)**

Parameter	Symbol	Limits	Unit		
Peak Pulse Power (tp = 8/20µs)	PPP	300	W		
Lead Solder Temperature - Maximum	TL	260	°C		
(10 Second Duration)					
Storage Temperature Range	Tstg	<b>-</b> 55∼+150	°C		
Operating Temperature Range	Тор	<b>-</b> 40∼+125	°C		
Maximum junction temperature	Tj	150	°C		
Electrostatic discharge	VPP		kV		
IEC61000-4-2 air discharge		15			
IEC61000-4-2 contact discharge		8			







# **ELECTRICAL CHARACTERISTICS (Ta= 25°C)**

Symbol	Parameter
VRM	Stand-off voltage
VBR	Breakdown voltage
VCL	Clamping voltage
IRM	Leakage current
IPPM	Peak pulse current

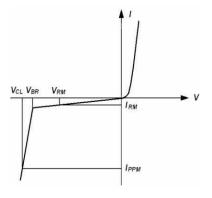


FIG1: Pulse Waveform

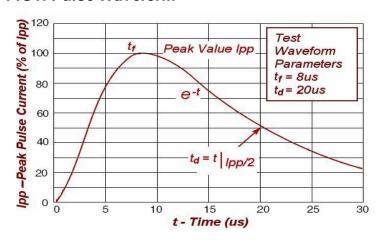
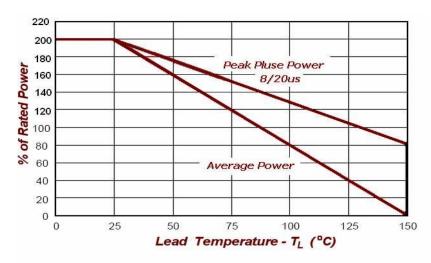


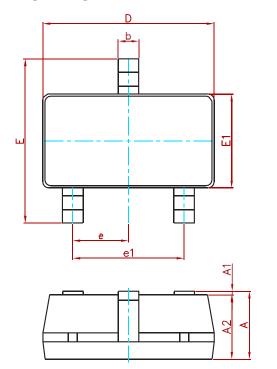
FIG2:Power Derating

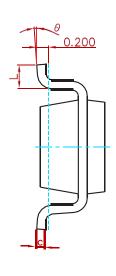




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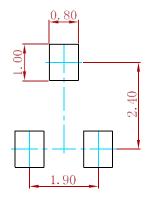
### **PACKAGE MECHANICAL DATA**





Symbol	Dimensions I	n Millimeters	Dimensions In Inches		
Syllibol	Min.	Max.	Min.	Max.	
Α	1.050	1.250	0.041	0.049	
A1	0.000	0.100	0.000	0.004	
A2	1.050	1.150	0.041	0.045	
b	0.300	0.500	0.012	0.020	
С	0.100	0.200	0.004	0.008	
D	2.820	3.020	0.111	0.119	
E1	1.500	1.700	0.059	0.067	
Е	2.650	2.950	0.104	0.116	
е	0.950(BSC)		0.037(BSC)		
e1	1.800	2.000	0.071	0.079	
L	0.300	0.600	0.012	0.024	
0	0°	8°	0°	8°	

# **Suggested Pad Layout**



- 1.Controlling dimension:in millimeters.
  2.General tolerance:± 0.05mm.
  3.The pad layout is for reference purposes only.

# **REEL SPECIFICATION**

P/N	PKG	QTY
SMXXT1G-MS	SOT-23	3000



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